





### **Features**

UL Recognized File # E-326243 ∻

<u>RoHS</u>

- ∻ Dual rectifier construction, positive center-tap
- ∻ Plastic package has Underwriters Laboratory Flammability Classifications 94V-0
- Metal silicon junction, majority carrier conduction ∻
- Low power loss, high efficiency ∻
- ∻ High current capability, low VF
- ∻ High surge reliabbility
- ∻ Epitaxial construction
- ∻ For use in low voltage, high frequency inventors, free wheeling, and polarity protection applications
- ∻ High temperature soldering guaranteed: 260°C/10 seconds, 0.17"(4.3mm) lead lengths at 5 lbs., (2.3kg) tension
- Green compound with suffix "G" on packing ∻ code & prefix "G" on datecode

## **Mechanical Data**

- Cases: JEDEC TO-3P/TO-247AD molded plastic ∻
- ∻ Terminals: Pure tin plated, lead free, solderable per MIL-STD-750, Method 2026
- ∻ Polarity: As marked
- ∻ Mounting position: Any
- Weight: 6.12 grams ∻

# Maximum Ratings and Electrical Characteristics

Rating at 25  $^\circ\!\!\mathbb{C}$  ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%

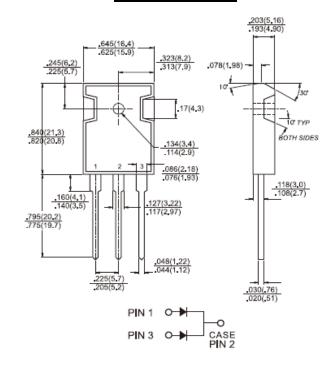
Type Number	Symbol	SR 3020 PT	SR 3030 PT	SR 3040 PT	SR 3050 PT	SR 3060 PT	SR 3090 PT	SR 30100 PT	SR 30150 PT	Units
Maximum Recurrent Peak Reverse Voltage	V <sub>RRM</sub>	20	30	40	50	60	90	100	150	V
Maximum RMS Voltage	V <sub>RMS</sub>	14	21	28	35	42	63	70	105	V
Maximum DC Blocking Voltage	V <sub>DC</sub>	20	30	40	50	60	90	100	150	V
Maximum Average Forward Rectified Current at T <sub>C</sub> =100°C	I <sub>F(AV)</sub>	30								А
Peak Forward Surge Current, 8.3 ms Single Half Sine- wave Superimposed on Rated Load (JEDEC method)	I <sub>FSM</sub>	300							А	
Maximum Instantaneous Forward Voltage (Note 1) @ 15 A	V <sub>F</sub>	0.55			0.	70 0.		90	1.00	V
Maximum DC Reverse Current @ $T_A=25$ °C		1.0 0.5								mA
at Rated DC Blocking Voltage @ T <sub>A</sub> =100°C	I <sub>R</sub>	20			15		10			mA
Typical Junction Capacitance (Note 2)	Cj	750		500			340		pF	
Typical Thermal Resistance Per Leg (Note 3)	R <sub>eJC</sub>	1.5								°C/W
Operating Junction Temperature Range	TJ	- 65 to + 125			- 65 to + 150					°C
Storage Temperature Range	T <sub>STG</sub>	- 65 to + 150								°C
Nate 1 - 200 va Dulas Width 20/ Duty Ovala										

Note 1: 300 us Pulse Width, 2% Duty Cycle

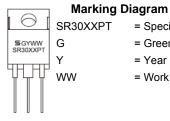
Note 2 : Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.

Note 3 : Mount Heatsink size of (4" x 6" x 0.25") Al-Plate.

# SR3020PT - SR30150PT 30.0AMPS. Schottky Barrier Rectifiers TO-3P/TO-247AD



## **Dimensions in inches and (millimeters)**

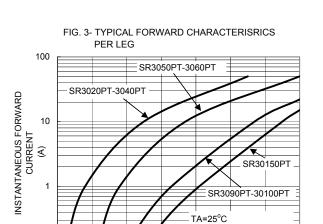


- = Specific Device Code
- = Green Compound
- = Year
- = Work Week



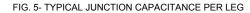
#### RATINGS AND CHARACTERISTIC CURVES (SR3020PT THRU SR30150PT)

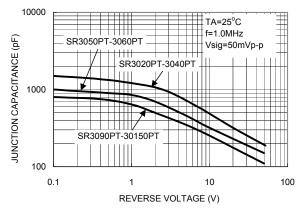
FIG. 1- FORWARD CURRENT DERATING CURVE 35 SR3050PT-30150PT 30 AVERAGE FORWARD 25 25 20 20 15 10 10 SR3020PT-3040PT 10 5 0 50 75 100 125 150 CASE TEMPERATURE. (°C)

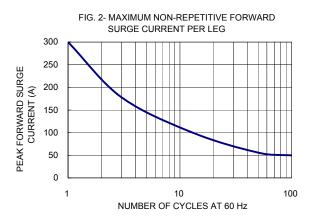


0.1 1% DUTY CYCLE 0.2 0.3 0.4 0.5 0.6 0.7 0.8 0.9 INSTANTANEOUS FORWARD VOLTAGE (V)

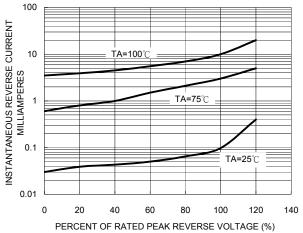
PULSE WIDTH-300uS

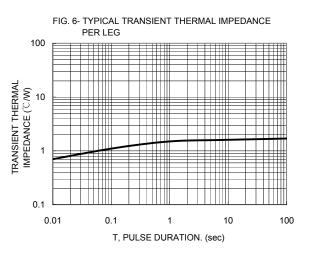












Version:D10

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